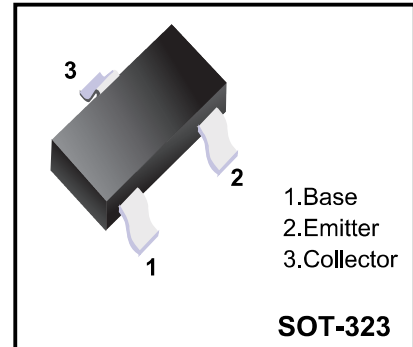


■ PNP Transistor

■ Features

- Ideally suited for automatic insertion
- Epitaxial planar die construction
- Complementary to BC817W



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

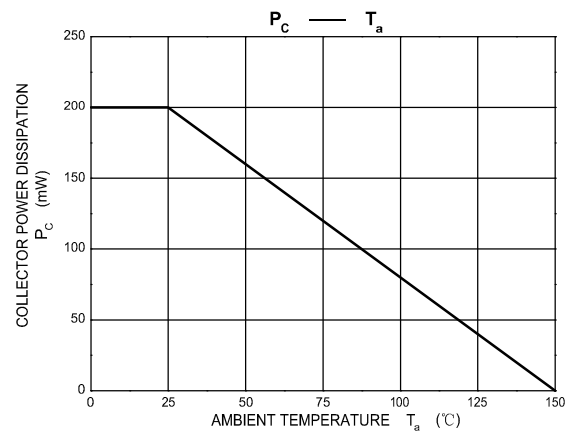
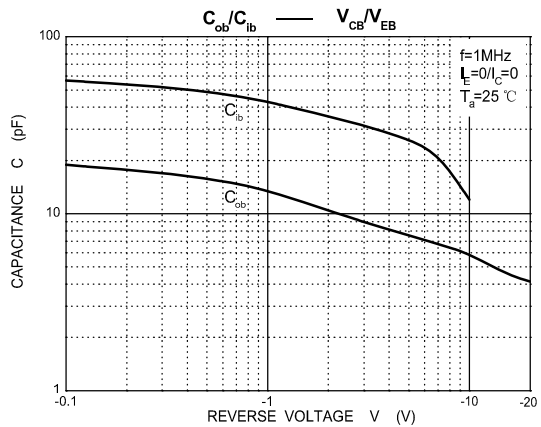
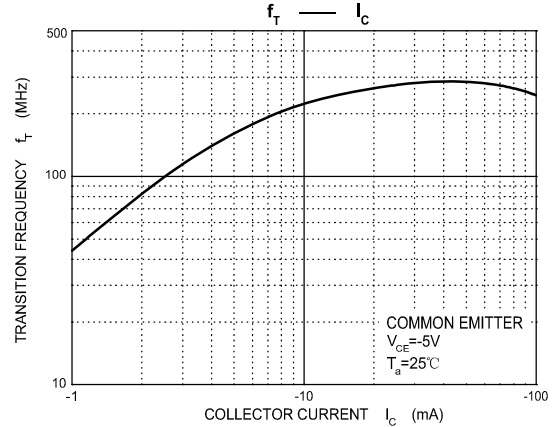
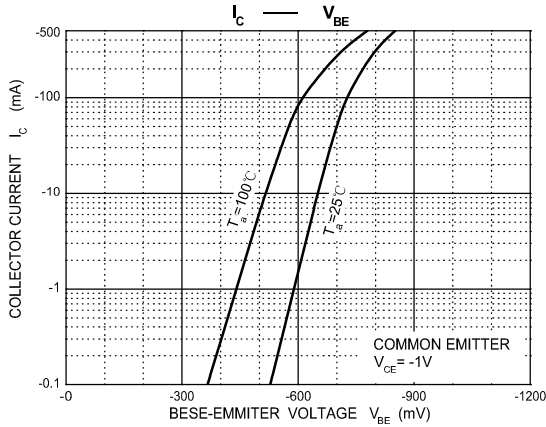
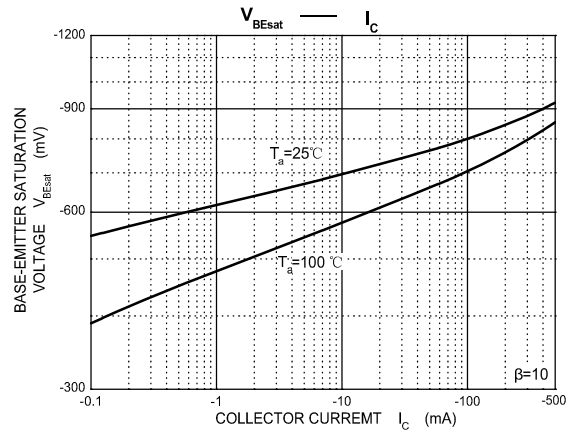
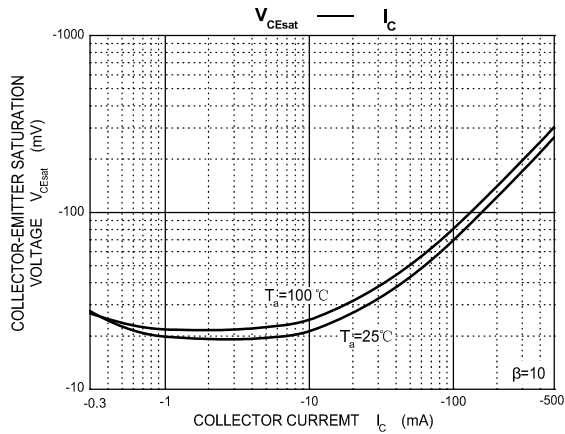
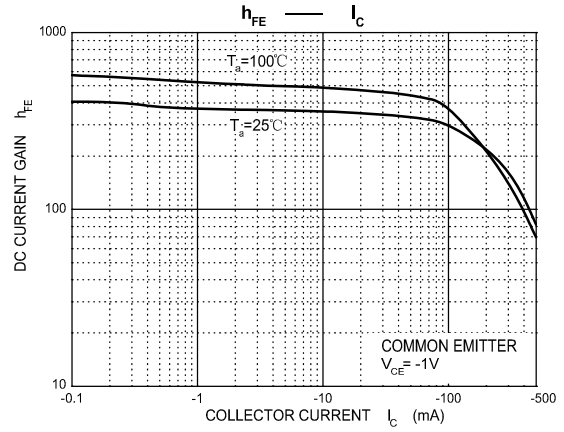
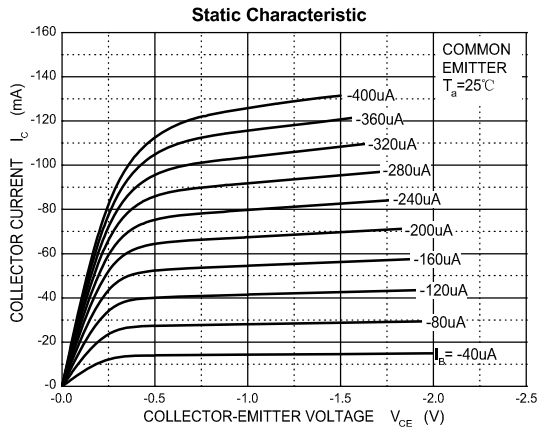
Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current -Continuous	-0.5	A
P_C	Collector Power Dissipation	0.2	W
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	625	$^\circ\text{C}/\text{W}$
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V_{CBO}	$I_C = -10\mu\text{A}, I_E = 0$	-50		V
Collector-emitter breakdown voltage	V_{CEO}	$I_C = -10\text{mA}, I_B = 0$	-45		V
Emitter-base breakdown voltage	V_{EBO}	$I_E = -1\mu\text{A}, I_C = 0$	-5		V
Collector cut-off current	I_{CBO}	$V_{CB} = -20\text{V}, I_E = 0$		-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$		-0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = -1\text{V}, I_C = -100\text{mA}$	100	600	
	$h_{FE(2)}$	$V_{CE} = -1\text{V}, I_C = -500\text{mA}$	40		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$		-0.7	V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE} = -1\text{V}, I_C = -500\text{mA}$		-1.2	V
Transition frequency	f_T	$V_{CE} = -5\text{V}, I_C = -10\text{mA}$ $f = 100\text{MHz}$	80		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{V}, f = 1\text{MHz}$		10	pF

■ Classification of $h_{FE(1)}$

Rank	BC807-16W	BC807-25W	BC807-40W
Range	100-250	160-400	250-600
Marking	5A	5B	5C



Ordering information

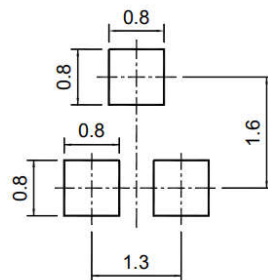
Package	Packing Description	Base Quantity	Packing Quantity
SOT-323	Tape/Reel, 7" reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

Package Dimensions

SOT-323

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	0.8	1.1	32	43
A1	0.1		4	
bp	0.3	0.4	12	16
C	0.10	0.25	4	10
D	1.8	2.2	71	87
E	1.15	1.35	45	53
E	1.3		51	
E1	0.65		26	
HE	2.0	2.2	79	87
Lp	0.15	0.45	6	18
Q	0.13	0.23	5.1	9
v	0.2		8	
W	0.2		8	

The recommended mounting pad size



Disclaimer

The information presented in this document is for reference only. Guangdong Youfeng Microelectronics Co.,Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise. The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), YFW or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale. This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <https://www.yfwdiode.com>, or consult YFW sales office for further assistance.